Diode Semiconductor Device - Page 1 of 1



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## **Inclosure Material:**

Metal

**Overall Length:** 

1.675 inches

**Mounting Facility Quantity:** 

1

#### Mounting Method:

Threaded stud

**Features Provided:** 

Hermetically sealed case

## **Overall Width Across Flats:**

Between 1.031 inches and 1.064 inches

Thread Size:

0.375 inches

Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

480.0 reverse voltage, dc and 400.0 working peak reverse voltage, peak total value

# **Current Rating Per Characteristic:**

75.00 amperes forward current, total rms megahertz

## Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius case

#### **Test Data Document:**

81349-mil-prf-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

## **Thread Series Designator:**

Unf

Terminal Type And Quantity:

1 tab, solder lug and 1 threaded stud

**Specification Data:** 

81349-mil-prf-19500/246 government specification

#### Shelf Life:

N/a

#### Unit Of Measure:

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# Demilitarization:

No

Fiig:

A110a0

## Mil-std (military Standard):

Mil-prf-19500 spec.